

SS52L THRU SS520L

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

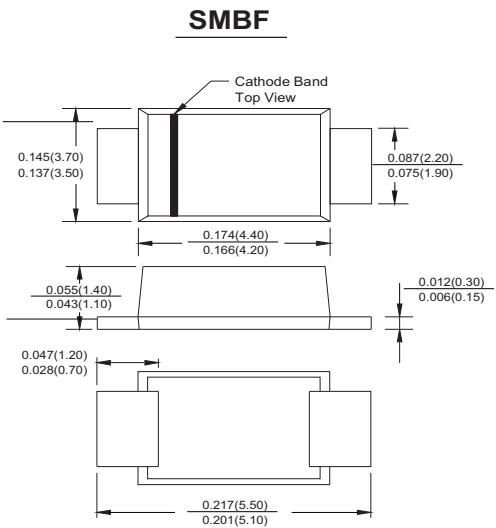
Forward Current - 5.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- For surface mount applications
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- Low profile package
- Built-in strain relief ,ideal for automated placement
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260° C/10 seconds at terminals

MECHANICAL DATA

- Case : S M B F
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27 mg .00086 oz



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SS 52L	SS 53L	SS 54L	SS 56L	SS 57L	SS 58L	SS 510L	SS 515L	SS 520L	Units							
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts							
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	57	71	105	140	Volts							
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts							
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I _(AV)	5.0								Amps								
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _J)	I _{FSM}	150.0								Amps								
Maximum instantaneous forward voltage at 5.0 A(Note 1)	V _F	0.45		0.50		0.6		0.80		0.85								
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	0.2								mA							
Typical junction capacitance(Note 3)	C _J		50		10													
Typical thermal resistance (Note 2)	R _{θJA} R _{θJL}	55.0 17.0								°C/W								
Operating junction temperature range	T _J	-65 to +150								°C								
Storage temperature range	T _{TSG}	-65 to +150								°C								

Notes: 1. Pulse test: 300 μ s pulse width, 1% duty cycle

2. P.C.B. mounted 0.55X0.55"(14X14mm) copper pad areas

3. Measured at 1MHz and reverse voltage of 4.0 volts

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FIG.1-FORWARD CURRENT DERATING CURVE

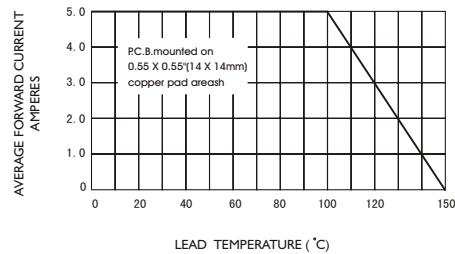


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

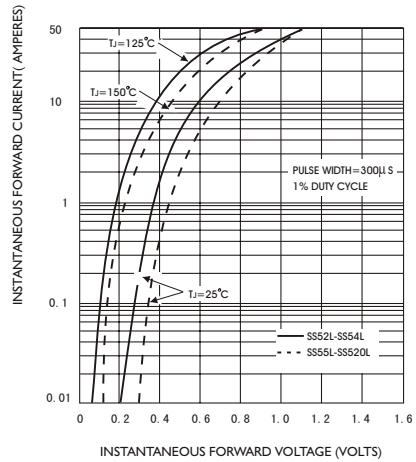


FIG.5-TYPICAL JUNCTION CAPACITANCE

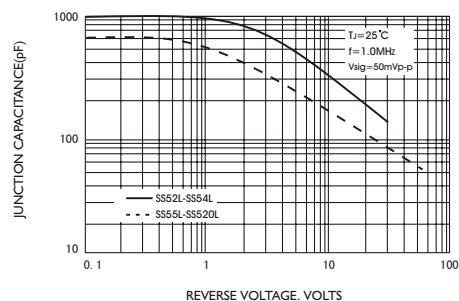


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

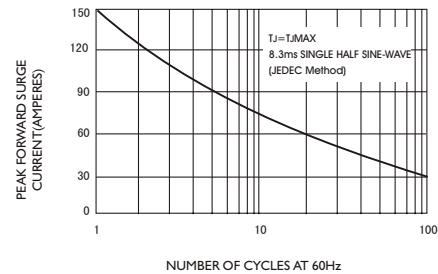


FIG.4-TYPICAL REVERSE CHARACTERISTICS

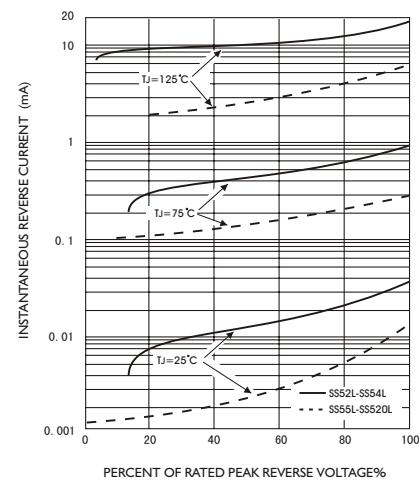


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

